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Physics and Technology of Semiconductor Thin Film-Based Active Elements and Devices

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About the ebook

The book features original results in studies and practical applications of A2B6-A4B6 and chalcogenide semiconductor compounds for sensory and micro(nano)electronics. Relevant experimental data as well as results of numerical simulations are also included.

Contents

- Semiconductor Structures: Basic Models and Experimental Results
- Meterostructure Growth
- Investigation of Electrical Properties of Active Elements Based on Silicon and A2B6-A4B6 Group Materials
- Engineering of Semiconductor-Based Active Elements by Mechanical Deformation and Ion Implantation Technology
- New Narrow-gap Semiconductor ZnCdHgTe: Growth Technology and Principal Features of ZnCdHgTe-Based Structures
- Electric Field-Induced Characteristics of ZnCdHgTe Films Surface
- Chalcogenide Semiconductors for Sensor Applications

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